TOSHIBA Transistor Silicon NPN Epitaxial Planar Type

2SC4320

VHF~UHF Band Low Noise Amplifier Applications

- Low noise figure, high gain.
- NF = 1.1dB, $|S_{21e}|^2 = 15$ dB (f = 1 GHz)

Maximum Ratings (Ta = 25°C)

Characteristics	Symbol	Rating	Unit	
Collector-base voltage	V _{CBO}	20	V	
Collector-emitter voltage	V _{CEO}	10	V	
Emitter-base voltage	V _{EBO}	1.5	V	
Base current	Ι _Β	20	mA	
Collector current	۱ _C	40	mA	
Collector power dissipation	P _C	150	mW	
Junction temperature	Тj	125	°C	
Storage temperature range	T _{stg}	-55~125	°C	



Weight: 0.012 g (typ.)

Microwave Characteristics (Ta = 25°C)

Characteristics Sy		Test Condition	Min	Тур.	Max	Unit	
Transition frequency	f _T	$V_{CE} = 8 \text{ V}, I_{C} = 20 \text{ mA}$	7	10	_	GHz	
Insertion gain	$ S_{21e} ^2$ (1)	$V_{CE} = 8 \text{ V}, I_C = 20 \text{ mA}, f = 1 \text{ GHz}$	12	15	_	dB	
	S _{21e} ² (2)	$V_{CE} = 8 \text{ V}, I_{C} = 20 \text{ mA}, f = 2 \text{ GHz}$	_	9	—		
Noise figure	NF (1)	$V_{CE} = 8 \text{ V}, I_C = 5 \text{ mA}, f = 1 \text{ GHz}$	_	1.1	2.5	dP	
	NF (2)	$V_{CE} = 8 \text{ V}, I_C = 5 \text{ mA}, f = 2 \text{ GHz}$	_	1.7	—	UD	

Electrical Characteristics (Ta = 25°C)

Characteristics	Test Condition	Min	Тур.	Max	Unit	
Collector cut-off current	I _{CBO}	$V_{CB} = 10 \text{ V}, \text{ I}_{E} = 0$			1	μA
Emitter cut-off current		$V_{EB} = 1 V, I_{C} = 0$		_	1	μA
DC current gain	h _{FE}	$V_{CE} = 8 \text{ V}, I_{C} = 20 \text{ mA}$	50	—	250	
Output capacitance	C _{ob}	$V_{00} = 10 V_{0} = 0$ f = 1 MHz (Note)	_	0.75	—	pF
Reverse transfer capacitance	C _{re}	VCB = 10 V, 1E = 0, 1 = 10012 (Note)	_	0.45	0.9	pF

Note: Cre is measured by 3 terminal method with capacitance bridge.

Marking









S-Parameter $Z_O = 50 \Omega$, Ta = 25°C

$V_{CE} = 8 V$, $I_C = 5 mA$

Frequency	S	11	S2	21	S1	2	S	22
MHz	MAG	ANG	MAG	ANG	MAG	ANG	MAG	ANG
200	0.764	-49.6	11.754	147.1	0.047	64.2	0.869	-29.4
400	0.624	-87.9	8.966	124.6	0.072	48.9	0.669	-48.3
600	0.532	-115.7	6.947	110.5	0.084	42.1	0.526	-59.5
800	0.485	-137.5	5.581	100.4	0.091	39.3	0.429	-66.6
1000	0.446	-155.0	4.636	92.9	0.097	38.6	0.370	-71.3
1200	0.441	-169.2	4.003	86.3	0.102	38.8	0.330	-75.3
1400	0.432	177.1	3.487	80.1	0.107	39.6	0.305	-77.6
1600	0.426	166.1	3.144	75.1	0.114	40.1	0.288	-80.7
1800	0.431	154.4	2.900	70.0	0.119	41.9	0.276	-83.9
2000	0.425	145.2	2.652	65.5	0.127	43.1	0.272	-87.3

$V_{CE} = 8 V$, $I_C = 20 mA$

Frequency	S	11	S2	21	S 1	2	S2	22
MHz	MAG	ANG	MAG	ANG	MAG	ANG	MAG	ANG
200	0.540	-90.3	21.037	129.7	0.033	55.7	0.670	-46.8
400	0.479	-134.8	13.017	108.7	0.046	50.0	0.417	-64.5
600	0.461	-159.4	9.230	98.1	0.054	51.2	0.297	-71.9
800	0.454	-176.0	7.117	90.5	0.063	54.1	0.230	-75.4
1000	0.454	170.7	5.816	85.1	0.073	56.1	0.191	-76.7
1200	0.452	160.0	4.944	79.8	0.084	57.9	0.168	-77.0
1400	0.461	149.1	4.299	74.7	0.094	58.7	0.156	-75.7
1600	0.459	140.7	3.838	70.6	0.105	59.0	0.151	-75.8
1800	0.461	131.9	3.483	66.0	0.117	59.4	0.154	-76.6
2000	0.450	124.2	3.171	61.8	0.130	59.0	0.161	-79.3

30°

-30°







 S_{22e} $V_{CE} = 8V$ $I_{C} = 5mA$ $Ta = 25^{\circ}C$



30°

30°









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